Preliminary Amendment
Application No.: 10/676,267
June 7, 2004

AMENDMENTS TO THE SPECIFICATION

Please delete the paragraphs beginning at page 1, line 3 and ending at page 1, line 13 to read as follows:

-- It is to be understood that although the present invention has been described with regard to preferred embodiments thereof, various other embodiments and variants may occur to those skilled in the art, which are within the scope and spirit of the invention, and such other embodiments and variants are intended to be covered by the following claims.

Text of Japanese application No. 2002 246573 filed on August 27, 2002, and Japanese priority application No. 2003 300714 filed on August 27, 2003 are hereby incorporated by reference. --

Please substitute the paragraph beginning at page 8, line 10 and ending at page 8, line 12 to read as follows:

-- FIG. 6 is a FIGS. 6A-6C are schematic view views showing the electrode structure of the nitride semiconductor device according to an embodiment according to the present invention. --

Preliminary Amendment
Application No.: 10/676,267
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Please substitute the paragraph beginning at page 8, line 22 and ending at page 9, line 1 to read as follows:

-- FIG. 9 is a FIGS. 9A-9C are schematic view views showing the structure of the nitride semiconductor device according to an embodiment of the present invention. --

Please insert the paragraphs at page 57, line 20 to read as follows:

-- It is to be understood that although the present invention has been described with regard to preferred embodiments thereof, various other embodiments and variants may occur to those skilled in the art, which are within the scope and spirit of the invention, and such other embodiments and variants are intended to be covered by the following claims.

Text of Japanese application No. 2002-246573 filed on August 27, 2002, and Japanese priority application No. 2003-300714 filed on August 26, 2003 are hereby incorporated by reference. --